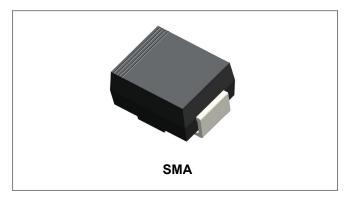






# S1A THRU S1M 1.0A SURFACE MOUNT GLASS PASSIVATED RECTIFIER



#### **Features**

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop
- Low Power Loss
- Built-in Strain Relief
- Plastic Case Material has UL Flammability Classification Rating 94V-0
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



### **Mechanical Data**

- Case: SMA molded plastic body
- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
- · Polarity: Color band denotes cathode end
- Mounting Position: AnyWeight: 0.06 grams

#### Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Type Number	Symbol	S1A	S1B	S1D	S1G	S1J	S1K	S1M	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Average Rectified Output Current @T <sub>L</sub> = 100°C	lo	1.0				Α			
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	Іғѕм	30			А				
Forward Voltage @ I <sub>F</sub> = 1.0 A	V <sub>F</sub>				1.10				V
Peak Reverse Current @T <sub>A</sub> = 25°C At Rated DC Blocking Voltage @T <sub>A</sub> = 125°C	I <sub>RM</sub>				5.0 200				μA
Reverse Recovery Time(Note1)	t <sub>rr</sub>				2.5				μS
Typical Junction Capacitance(Note2)	Сл				15				pF
Typical Thermal Resistance Junction to Lead (Note 3)		30				°C/W			
Operating and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>			-65	to +175				°C

Note: 1. Reverse recovery condition IF=0.5A, IR=1.0A, Irr=0.25A

- 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
- 3. Mounted on P.C.B.with 8.0mm<sup>2</sup> land areas.
  - China Germany Korea Singapore United States •
  - http://www.smc-diodes.com
     sales@ smc-diodes.com







# **Ratings and Characteristics Curves**

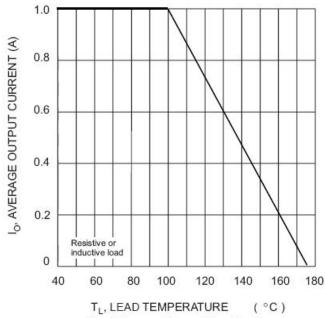
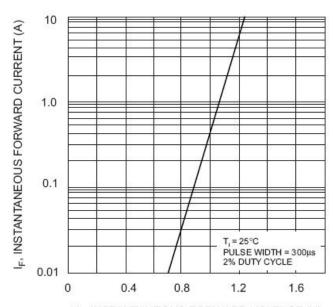
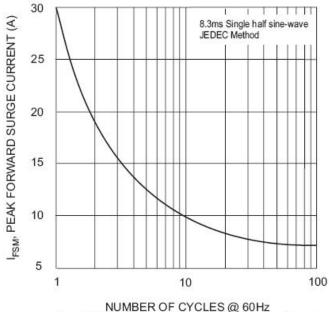


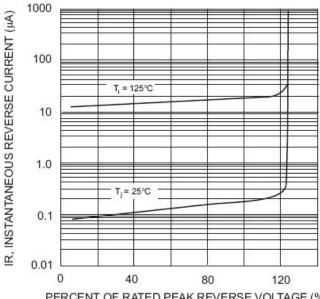
Fig. 1 Forward Current Derating Curve



V<sub>F</sub>, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics



NUMBER OF CYCLES @ 60Hz
Fig. 3 Max Non-Repetitive Peak Fwd Surge Current



PERCENT OF RATED PEAK REVERSE VOLTAGE (%) Fig. 4 Typical Reverse Characteristics

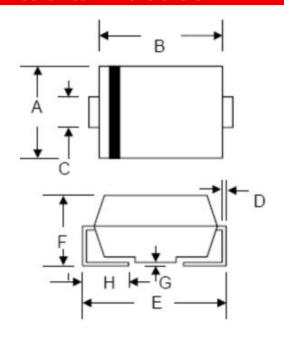
- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •







### **Mechanical Dimensions SMA**



SYMBOL		neters	Inches			
SYMBOL	Min.	Max.	Min.	Max.		
А	2.40	2.84	0.094	0.112		
В	3.99	4.75	0.157	0.187		
С	1.05	1.70	0.041	0.067		
D	0.15	0.51	0.006	0.020		
Е	4.80	5.66	0.189	0.223		
F	1.90	2.95	0.075	0.116		
G	0.05	0.203	0.002	0.008		
Н	0.76	1.52	0.030	0.600		

## **Ordering Information**

Device	Package	Shipping
S1A-S1M	SMA (Pb-Free)	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



Where XXXXX is YYWWL

 S1A
 = Type Number

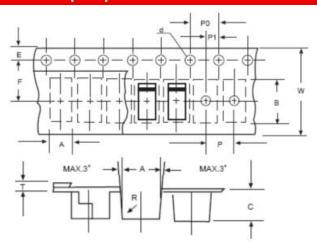
 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

## **Carrier Tape Specification SMA**



SYMBOL	Millimeters			
	Min.	Max.		
Α	2.97	3.17		
В	5.70	5.90		
С	2.32	2.52		
d	1.40	1.60		
E	1.40	1.60		
F	5.60	5.70		
Р	3.90	4.10		
P0	3.90	4.10		
P1	1.90	2.10		
Т	0.25	0.35		
W	11.80	12.20		

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •







#### DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Sangdest Microelectronics (Nanjing) Co., Ltd.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Sangdest Microelectronics (Nanjing) Co., Ltd.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Diodes - General Purpose, Power, Switching category:

Click to view products by Sangdest manufacturer:

Other Similar products are found below:

MCL4151-TR3 MMBD3004S-13-F RD0306T-H RGP30G-E373 BAQ333-TR BAQ335-TR BAQ33-GS18 BAS1602VH6327XT BAV17-TR BAV19-TR BAV301-TR BAW27-TAP NSVBAV23CLT1G NTE525 1SS181-TP 1SS184-TP 1SS193,LF 1SS193-TP 1SS400CST2RA SBAV99LT3G SDAA13 LL4448-GS18 SHN2D02FUTW1T1G LS4150GS18 LS4151GS08 SMMBD7000LT3G 1N4449 1N4934-E3/73 APT100DL60HJ RFUH20TB3S RGP30G-E354 RGP30M-E3/73 D291S45T MCL4151-TR BAS 16-02L E6327 BAS 16-02V H6327 BAS 28 E6327 BAS33-TAP BAS 70-02V H6327 BAV300-TR BAV303-TR3 BAW27-TR BAW56DWQ-7-F BAW56M3T5G BAW75-TAP BAW76-TR MM230L-CAA MMSD914-TP IDW40E65D1